



A Product Line of Diodes Incorporated



BCW66H

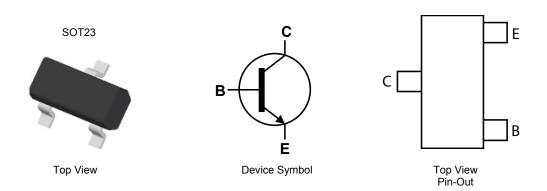
#### **45V NPN SMALL SIGNAL TRANSISTOR IN SOT23**

#### Features

- BV<sub>CEO</sub> > 45V
- I<sub>C</sub> = 800mA High Continuous Collector Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 300mV @ 100mA</li>
- Complementary PNP Type: BCW68H
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

#### **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Weight 0.008 grams (approximate)



### Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCW66HTA	AEC-Q101	EH	7	8	3,000
BCW66HQTA	Automotive	EH	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**







## BCW66H

### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	75	V
Collector-Emitter Voltage	V <sub>CEO</sub>	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ι <sub>C</sub>	800	mA
Peak Pulse Current	I <sub>CM</sub>	1000	mA
Base Current	IB	100	mA

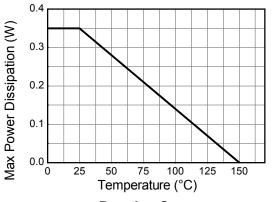
# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

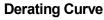
Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	D-	310	mW	
	(Note 7)	PD	350	IIIVV	
Thermal Resistance, Junction to Ambient	(Note 6)		403	°C/W	
	(Note 7)	R <sub>θJA</sub>	357	-0/10	
Thermal Resistance, Junction to Leads	(Note 8)	R <sub>0JL</sub>	350	°C/W	
Operating and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150	°C	

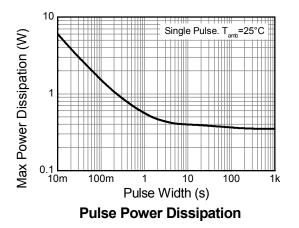
6. For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state.

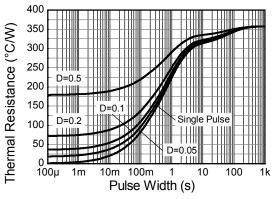
7. Same as Note 6, except the device is mounted on 15mm X 15mm 1oz copper.

8. Thermal resistance from junction to solder-point (at the end of the leads).









**Transient Thermal Impedance** 





BCW66H

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

						-
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	<b>BV</b> <sub>CES</sub>	75	—	—	V	I <sub>C</sub> = 10μA
Collector-Emitter Breakdown Voltage (base open) (Note 9)	BV <sub>CEO</sub>	45	_	—	V	I <sub>CEO</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	_	_	V	I <sub>EBO</sub> = 10μA
Collector-Emitter Cut-Off Current	ICES		<1 —	20 20	nA μA	V <sub>CES</sub> = 45V V <sub>CES</sub> = 45V, T <sub>A</sub> = +150°C
Emitter-Base Cut-Off Current	I <sub>EBO</sub>		<1	20	nA	V <sub>EBO</sub> = 5.6V
ON CHARACTERISTICS (Note 9)	•		•	•		
Static Forward Current Transfer Ratio	h <sub>FE</sub>	80 180 250 100	 350	 630	_	$I_{C} = 100 \mu A, V_{CE} = 10V$ $I_{C} = 10 m A, V_{CE} = 1V$ $I_{C} = 100 m A, V_{CE} = 1V$
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—		0.3	mV	$\label{eq:lc} \begin{array}{l} I_{C} = 500 \text{mA}, \ V_{CE} = 2 \text{V} \\ \\ I_{C} = 100 \text{mA}, \ I_{B} = 10 \text{mA} \\ \\ I_{C} = 500 \text{mA}, \ I_{B} = 50 \text{mA} \end{array}$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	_	_	2	V	$I_{\rm C} = 500$ mA, $I_{\rm B} = 50$ mA
SMALL SIGNAL CHARACTERISTICS (Note 9)	DE(GUI)			1		0, 1
Transition Frequency	fT	100	_	_	MHz	I <sub>C</sub> = 20mA, V <sub>CE</sub> = 10V, f = 100MHz
Output Capacitance	Cobo		8	12	pF	V <sub>CB</sub> = 10V, f = 1MHz
Input Capacitance	Cibo		_	80	pF	V <sub>CB</sub> = -0.5V, f = 1MHz
Noise Figure	N	_	2	10	dB	$I_{C}$ = 0.2mA. $V_{CE}$ = 5V, R <sub>G</sub> = 1K $\Omega$
Turn-On Time	t <sub>on</sub>	—	—	100	ns	$I_{\rm C} = 150 {\rm mA}.$
Turn-Off Time	t <sub>off</sub>	_	—	400	ns	$I_{B1} = -I_{B2} = 15mA$ $R_L = 150\Omega$

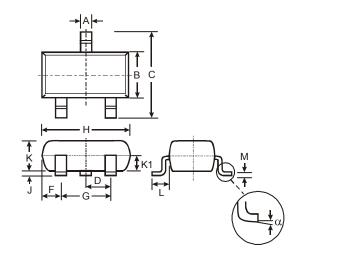
Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%





# **Package Outline Dimensions**

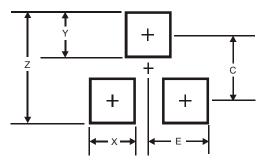
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
К	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35





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